

- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: >4000 V
– Machine Model: >400 V
- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

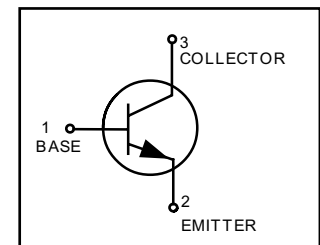
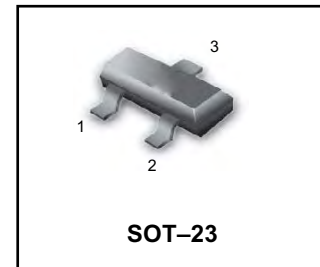
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage BC846 BC847, BC850 BC848, BC849	V_{CEO}	65 45 30	Vdc
Collector–Base Voltage BC846 BC847, BC850 BC848, BC849	V_{CBO}	80 50 30	Vdc
Emitter–Base Voltage BC846 BC847, BC850 BC848, BC849	V_{EBO}	6.0 6.0 5.0	Vdc
Collector Current – Continuous	I_C	100	mAdc

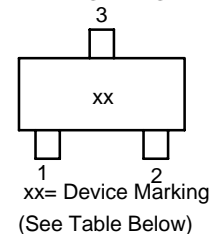
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225	mW
Thermal Resistance, Junction to Ambient (Note 1.)	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate (Note 2.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300	mW
Thermal Resistance, Junction to Ambient (Note 2.)	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

1. FR–5 = 1.0 x 0.75 x 0.062 in
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



MARKING DIAGRAM



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Package	Shipping
BC846ALT1G S-BC846ALT1G	1A	SOT-23	3000/Tape&Reel
BC846ALT3G S-BC846ALT3G	1A	SOT-23	10000/Tape&Reel
BC846BLT1G BC846BLT1G	1B	SOT-23	3000/Tape&Reel
BC846BLT3G S-BC846BLT3G	1B	SOT-23	10000/Tape&Reel
BC847ALT1G S-BC847ALT1G	1E	SOT-23	3000/Tape&Reel
BC847ALT3G S-BC847ALT3G	1E	SOT-23	10000/Tape&Reel
BC847BLT1G S-BC847BLT1G	1F	SOT-23	3000/Tape&Reel
BC847BLT3G S-BC847BLT3G	1F	SOT-23	10000/Tape&Reel
BC847CLT1G S-BC847CLT1G	1G	SOT-23	3000/Tape&Reel
BC847CLT3G S-BC847CLT3G	1G	SOT-23	10000/Tape&Reel
BC848ALT1G S-BC848ALT1G	1J	SOT-23	3000/Tape&Reel
BC848ALT3G S-BC848ALT3G	1J	SOT-23	10000/Tape&Reel
BC848BLT1G S-BC848BLT1G	1K	SOT-23	3000/Tape&Reel
BC848BLT3G S-BC848BLT3G	1K	SOT-23	10000/Tape&Reel
BC848CLT1G S-BC848CLT1G	1L	SOT-23	3000/Tape&Reel
BC848CLT3G S-BC848CLT3G	1L	SOT-23	10000/Tape&Reel
BC849BLT1G S-BC849BLT1G	2B	SOT-23	3000/Tape&Reel
BC849BLT3G S-BC849BLT3G	2B	SOT-23	10000/Tape&Reel
BC849CLT1G S-BC849CLT1G	2C	SOT-23	3000/Tape&Reel
BC849CLT3G S-BC849CLT3G	2C	SOT-23	10000/Tape&Reel
BC850BLT1G S-BC850BLT1G	2E	SOT-23	3000/Tape&Reel
BC850BLT3G S-BC850BLT3G	2E	SOT-23	10000/Tape&Reel
BC850CLT1G S-BC850CLT1G	2G	SOT-23	3000/Tape&Reel
BC850CLT3G S-BC850CLT3G	2G	SOT-23	10000/Tape&Reel

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage ($I_C = 10\text{ mA}$)	BC846A,B BC847A,B,C, BC850B,C BC848A,B,C, BC849B,C	$V_{(BR)CEO}$	65 45 30	– – –	– – –	V
Collector–Emitter Breakdown Voltage ($I_C = 10\ \mu\text{A}$, $V_{EB} = 0$)	BC846A,B BC847A,B,C, BC850B,C BC848A,B,C, BC849B,C	$V_{(BR)CES}$	80 50 30	– – –	– – –	V
Collector–Base Breakdown Voltage ($I_C = 10\ \mu\text{A}$)	BC846A,B BC847A,B,C, BC850B,C BC848A,B,C, BC849B,C	$V_{(BR)CBO}$	80 50 30	– – –	– – –	V
Emitter–Base Breakdown Voltage ($I_E = 1.0\ \mu\text{A}$)	BC846A,B BC847A,B,C, BC850B,C BC848A,B,C, BC849B,C	$V_{(BR)EBO}$	6.0 6.0 5.0	– – –	– – –	V
Collector Cutoff Current ($V_{CB} = 30\text{ V}$) ($V_{CB} = 30\text{ V}$, $T_A = 150^\circ\text{C}$)		I_{CBO}	– –	– –	15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain ($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$)	BC846A, BC847A, BC848A BC846B, BC847B, BC848B, BC849B, BC850B BC847C, BC848C, BC849C, BC850C	h_{FE}	110 200 420	180 290 520	220 450 800	–
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)		$V_{CE(sat)}$	– –	– –	0.25 0.6	V
Base–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)		$V_{BE(sat)}$	– –	0.7 0.9	– –	V
Base–Emitter Voltage ($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$) ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}$)		$V_{BE(on)}$	580 –	660 –	700 770	mV
SMALL–SIGNAL CHARACTERISTICS						
Current–Gain – Bandwidth Product ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $f = 100\text{ MHz}$)		f_T	100	–	–	MHz
Output Capacitance ($V_{CB} = 10\text{ V}$, $f = 1.0\text{ MHz}$)		C_{obo}	–	–	4.5	pF
Noise Figure ($I_C = 0.2\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$)	BC846A,B, BC847A,B,C, BC848A,B,C BC849B,C, BC850B,C	NF	– –	– –	10 4.0	dB

BC846A, BC847A, BC848A

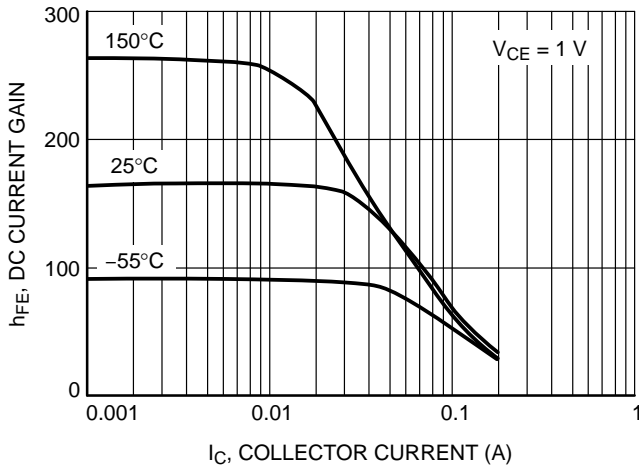


Figure 1. DC Current Gain vs. Collector Current

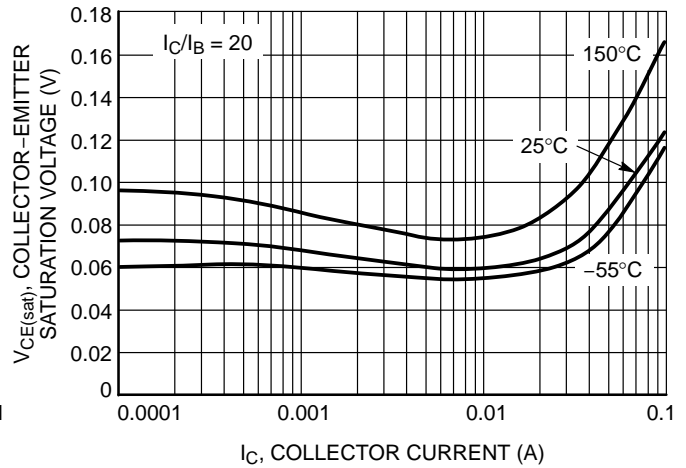


Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

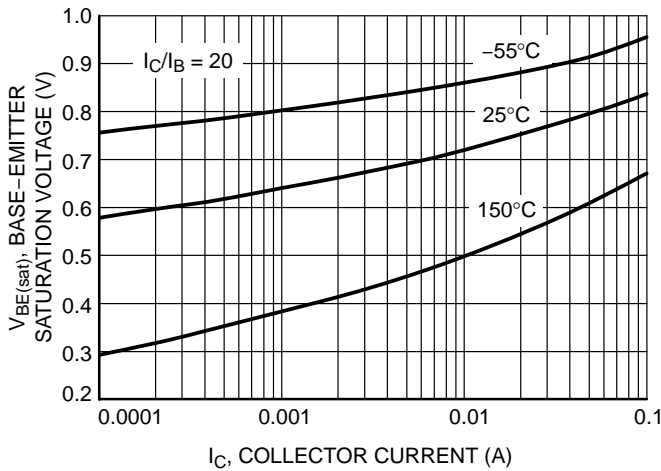


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

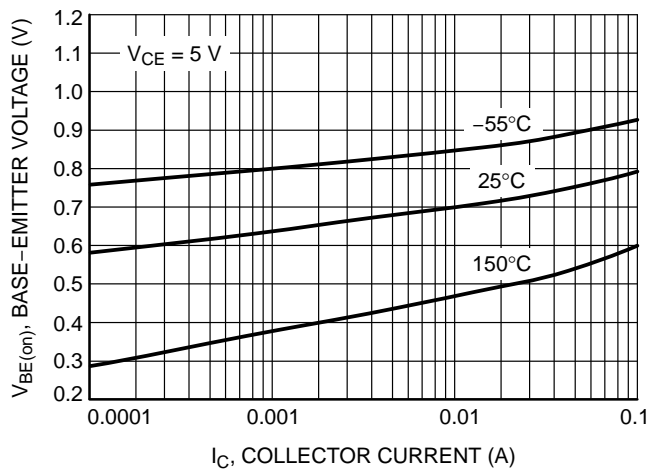


Figure 4. Base Emitter Voltage vs. Collector Current

BC846A, BC847A, BC848A

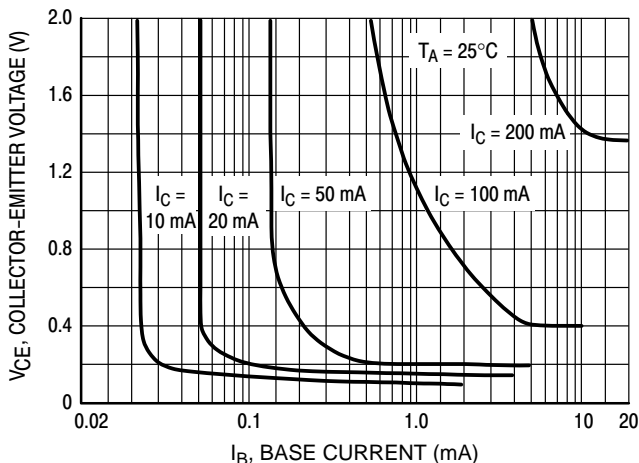


Figure 5. Collector Saturation Region

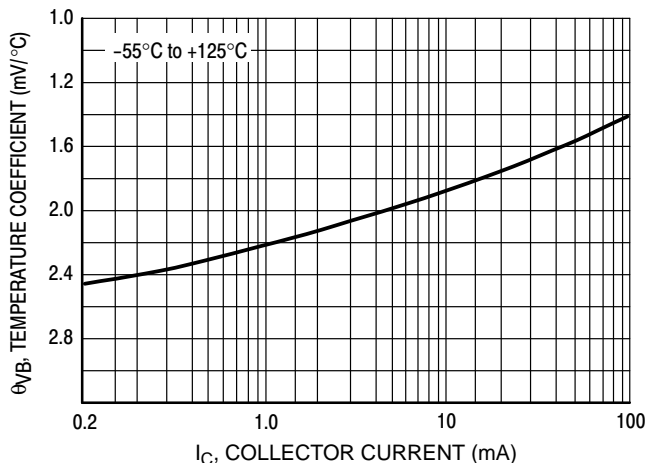


Figure 6. Base-Emitter Temperature Coefficient

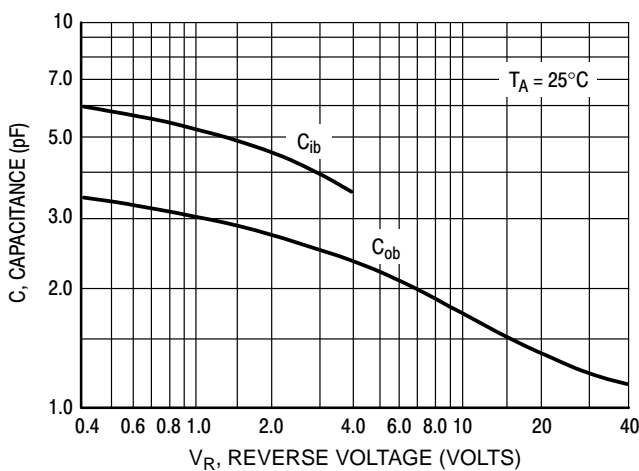


Figure 7. Capacitances

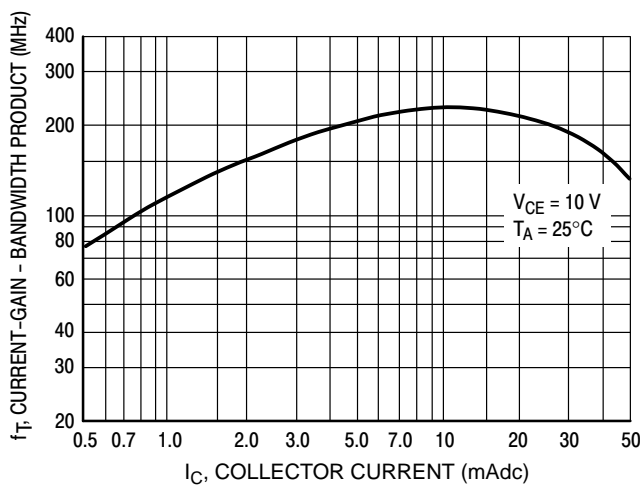


Figure 8. Current-Gain - Bandwidth Product

BC846B

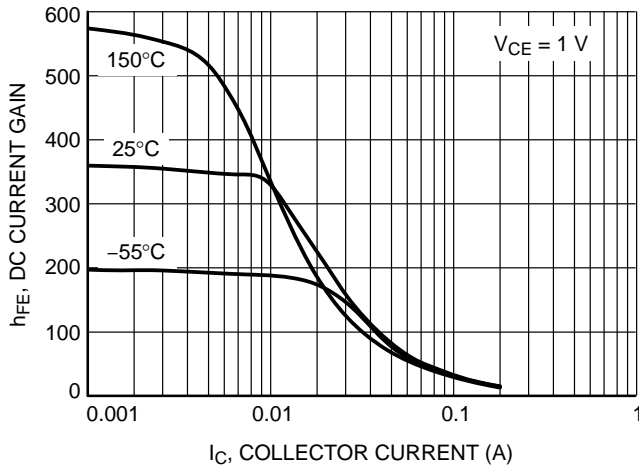


Figure 9. DC Current Gain vs. Collector Current

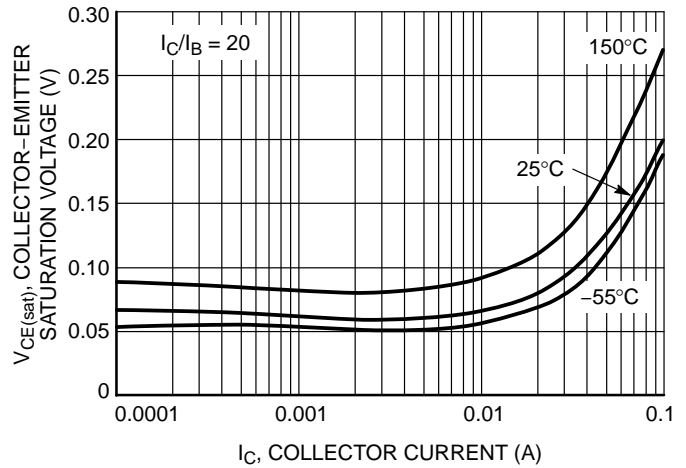


Figure 10. Collector Emitter Saturation Voltage vs. Collector Current

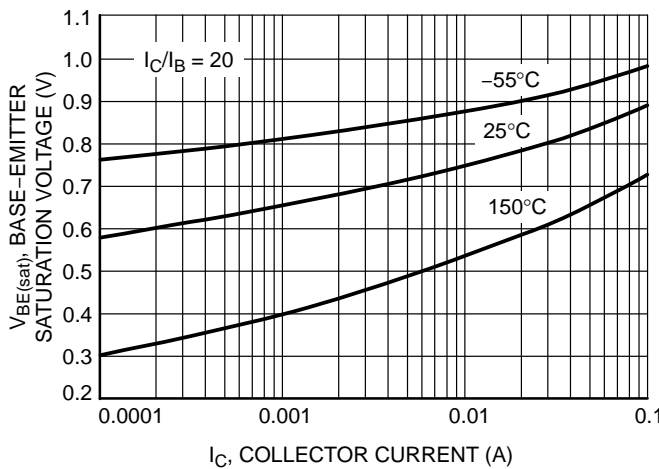


Figure 11. Base Emitter Saturation Voltage vs. Collector Current

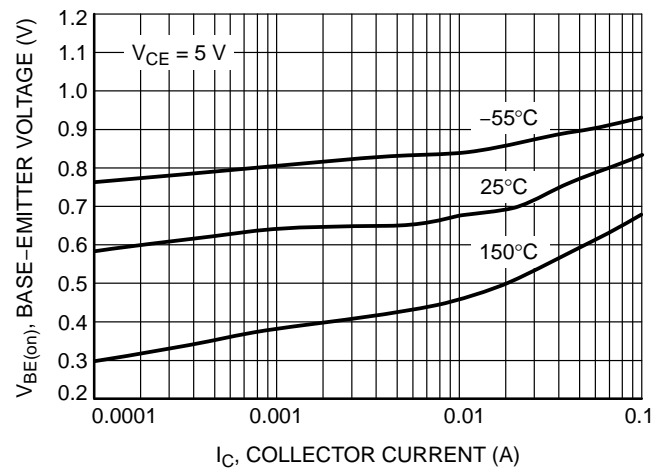


Figure 12. Base Emitter Voltage vs. Collector Current

BC846B

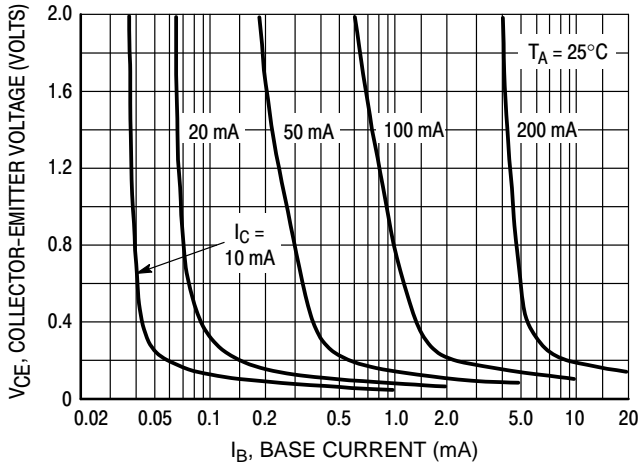


Figure 13. Collector Saturation Region

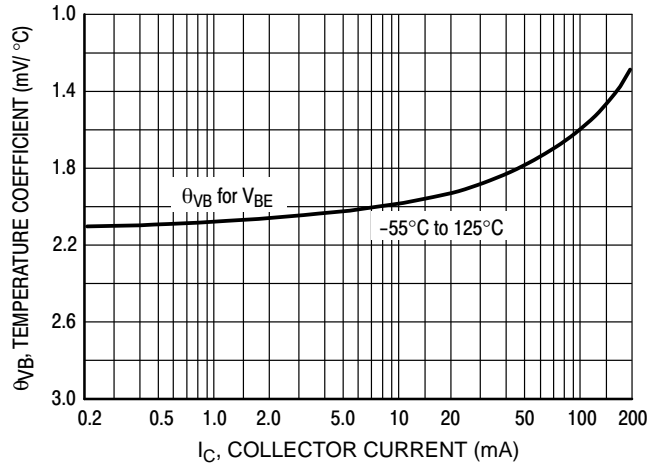


Figure 14. Base-Emitter Temperature Coefficient

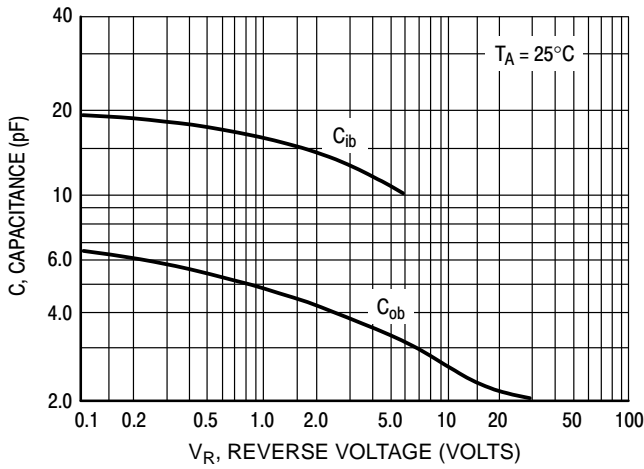


Figure 15. Capacitance

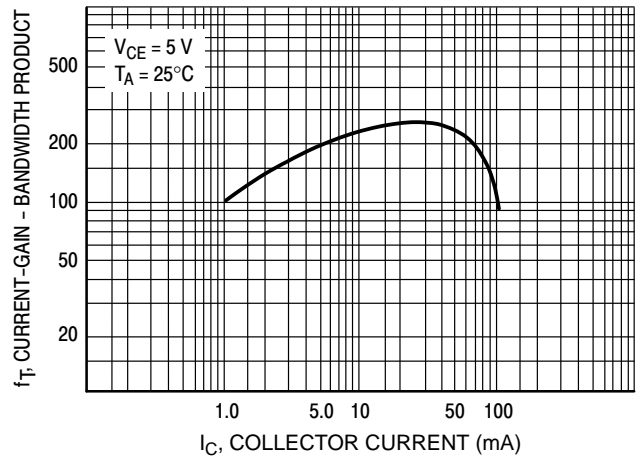


Figure 16. Current-Gain - Bandwidth Product

BC847B, BC848B, BC849B, BC850B

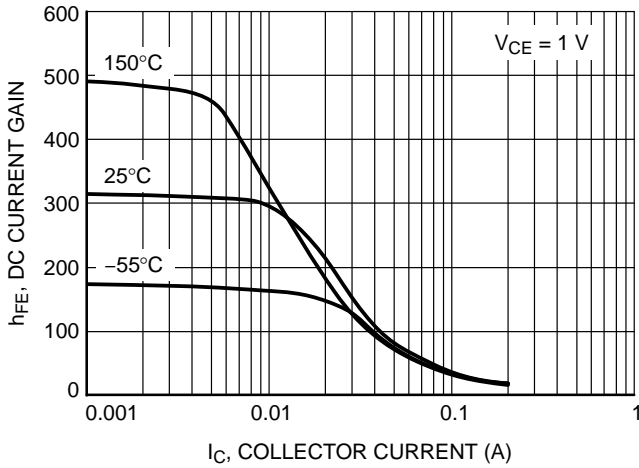


Figure 17. DC Current Gain vs. Collector Current

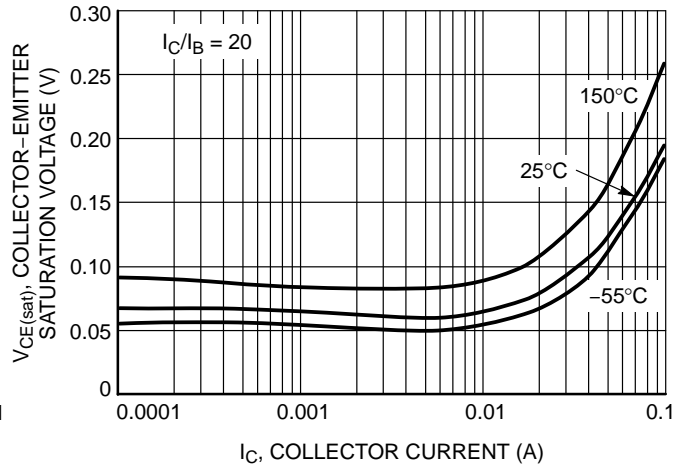


Figure 18. Collector Emitter Saturation Voltage vs. Collector Current

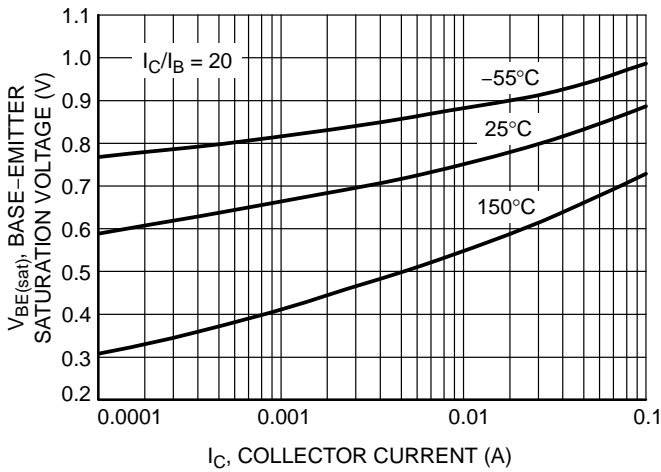


Figure 19. Base Emitter Saturation Voltage vs. Collector Current

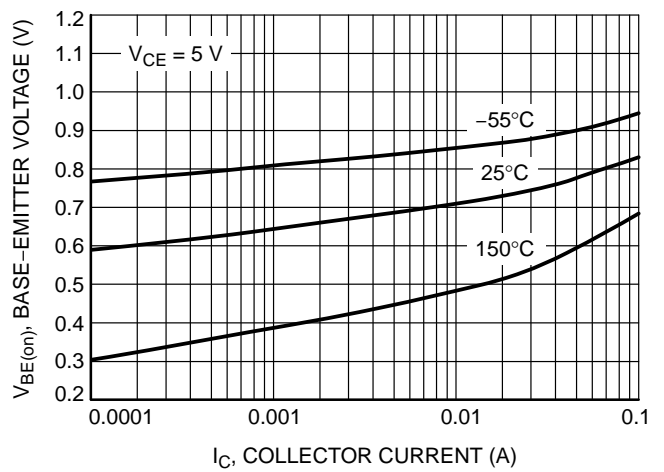


Figure 20. Base Emitter Voltage vs. Collector Current

BC847B, BC848B, BC849B, BC850B

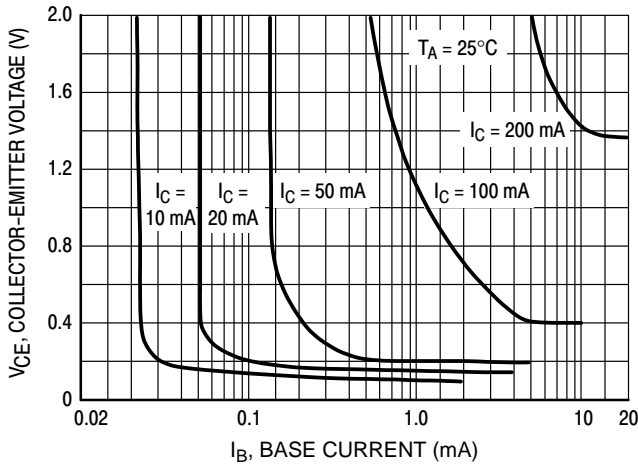


Figure 21. Collector Saturation Region

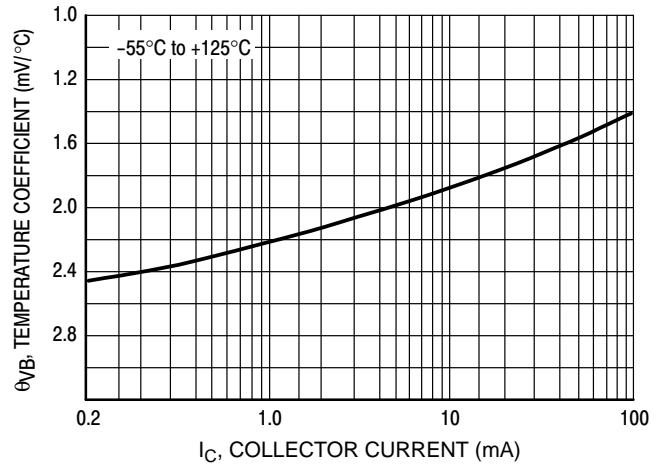


Figure 22. Base-Emitter Temperature Coefficient

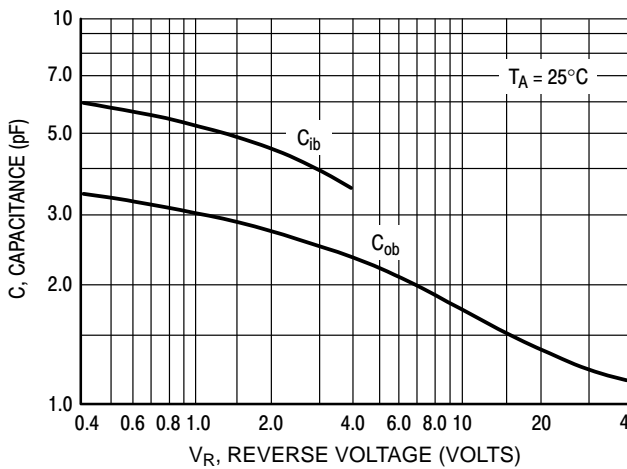


Figure 23. Capacitances

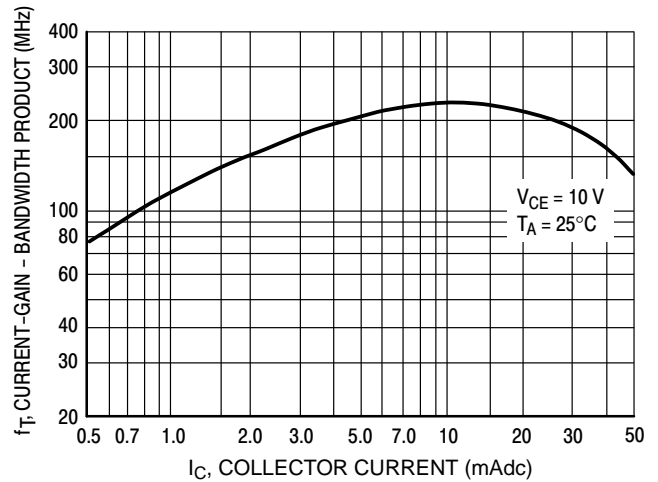


Figure 24. Current-Gain - Bandwidth Product

BC847C, BC848C, BC849C, BC850C

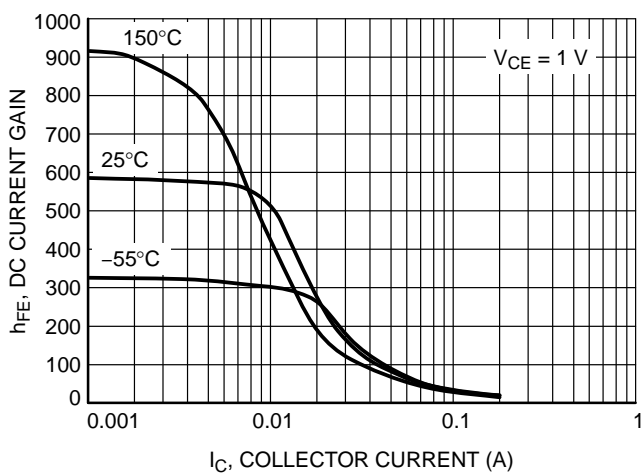


Figure 25. DC Current Gain vs. Collector Current

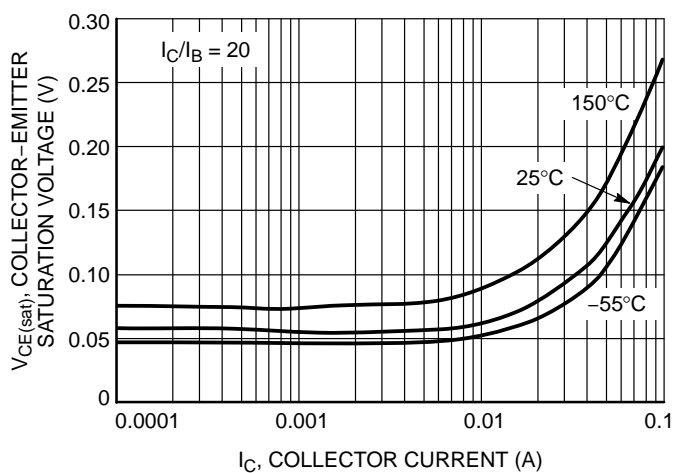


Figure 26. Collector Emitter Saturation Voltage vs. Collector Current

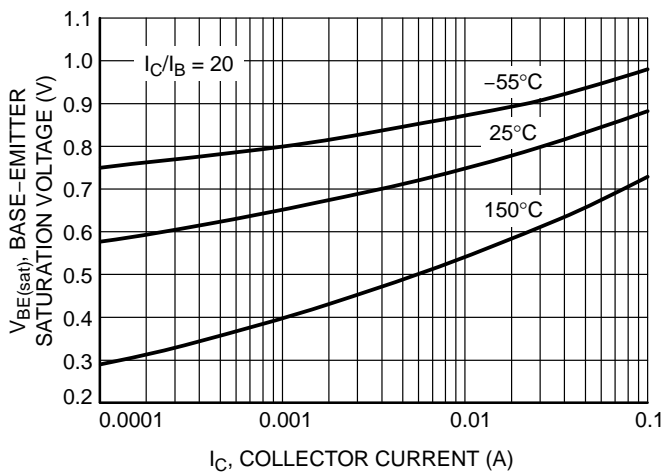


Figure 27. Base Emitter Saturation Voltage vs. Collector Current

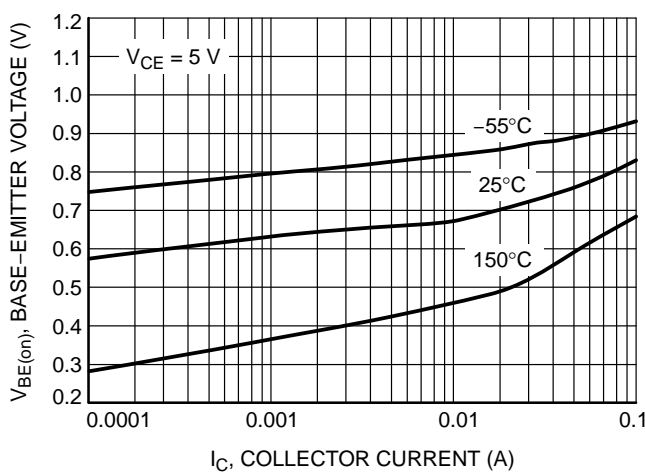


Figure 28. Base Emitter Voltage vs. Collector Current

BC847C, BC848C, BC849C, BC850C

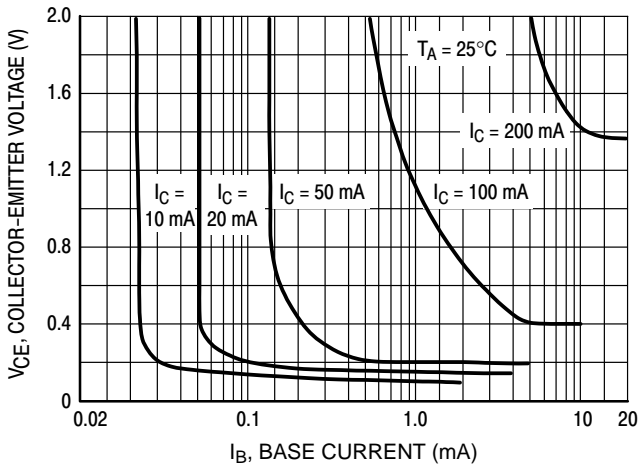


Figure 29. Collector Saturation Region

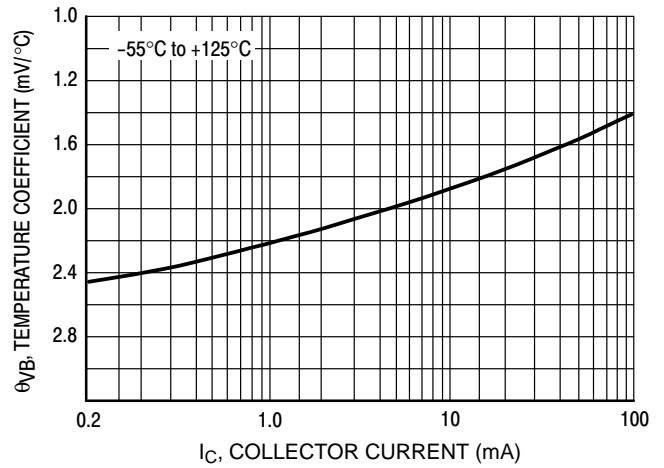


Figure 30. Base-Emitter Temperature Coefficient

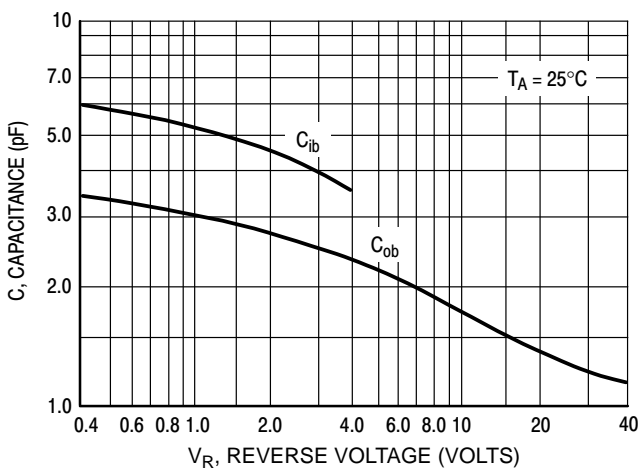


Figure 31. Capacitances

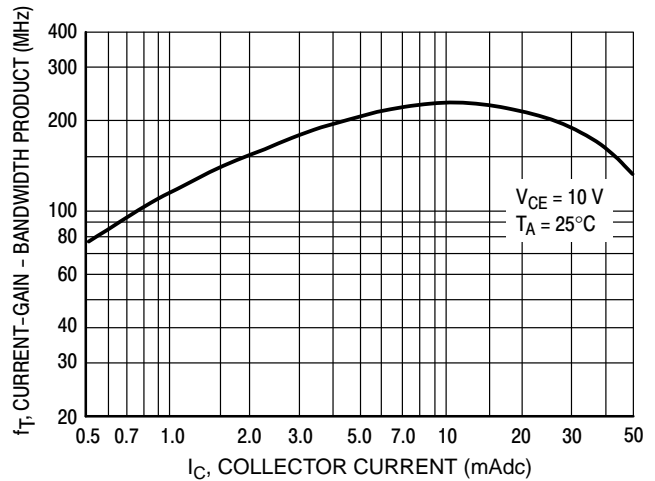


Figure 32. Current-Gain - Bandwidth Product

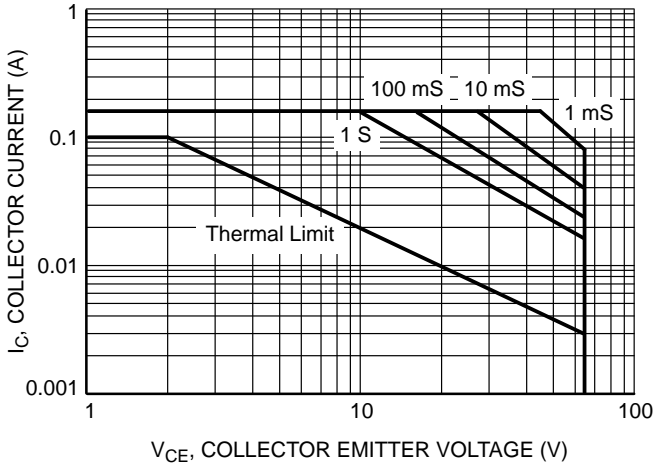


Figure 33. Safe Operating Area for LBC846A, LBC846B

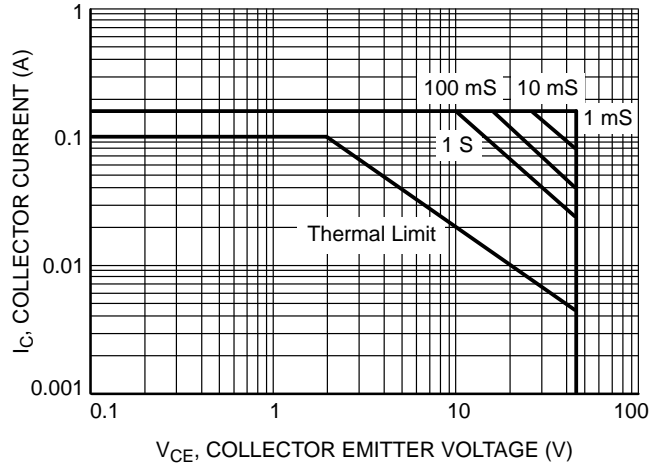


Figure 34. Safe Operating Area for LBC847A, LBC847B, LBC847C, LBC850B, LBC850C

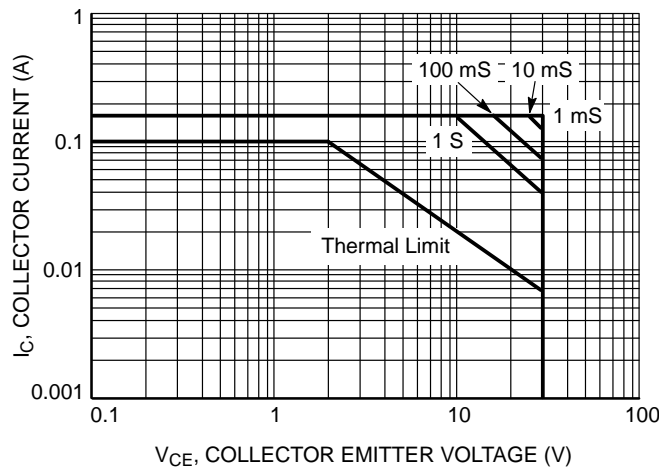
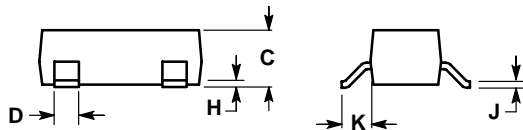
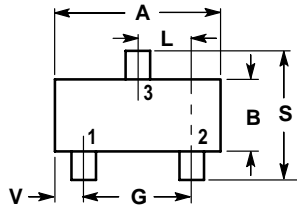


Figure 35. Safe Operating Area for LBC848A, LBC848B, LBC848C, LBC849B, LBC849C

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

